

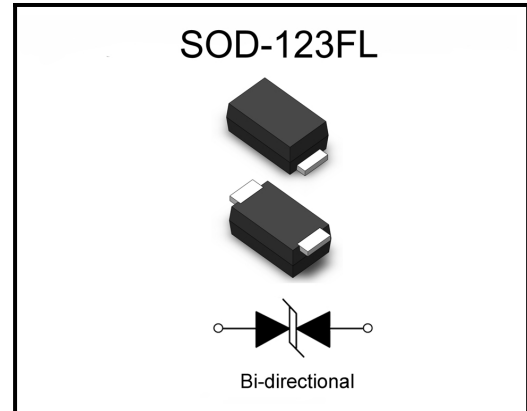
BSMF3.3CAH

TVS Protection Diode

Features

- 9300W Peak pulse power per line ($t_p = 8/20\mu s$)
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one power line
- IEC 61000-4-2 $\pm 30kV$ contact $\pm 30kV$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 550A (8/20 μs)

Package



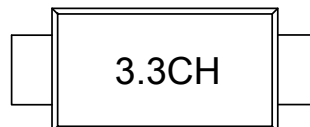
Mechanical Characteristics

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Applications

- SOD-123FL package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Marking



Ordering information

Order code	Package	Base qty	Delivery mode
BSMF3.3CAH	SOD-123FL	3000	Tape and reel

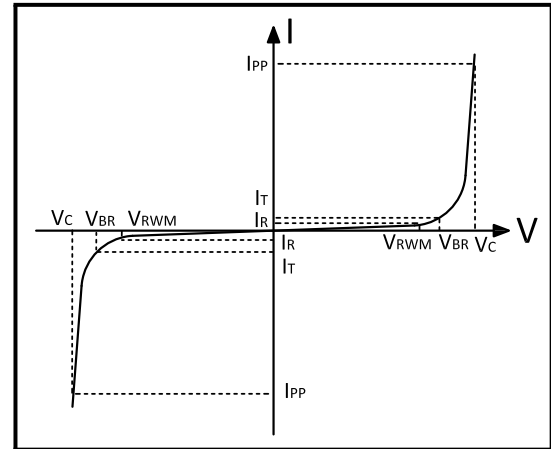


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TVS Protection Diode

Electrical Parameters ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}



Absolute Maximum Rating

Rating	Symler	Value	Units
Peak Pulse Power ($t_p = 8/20\mu\text{s}$)	P_{PP}	9300	Watts
Peak Pulse Current ($t_p = 8/20\mu\text{s}$)	I_{PP}	550	A
ESD per IEC 61000-4-2 (Air)	V_{ESD}	30	KV
ESD per IEC 61000-4-2 (Contact)		30	
Lead Soldering Temperature	T_L	260(10seconds)	$^\circ\text{C}$
Junction Temperature	T_J	-55 to + 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to + 150	$^\circ\text{C}$

Electrical Characteristics

Parameter	Symler	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}	—	—	—	3.3	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	4.0	—	7.0	V
Reverse Leakage Current	I_R	$V_{RWM} = 3.3\text{V}, T = 25^\circ\text{C}$	—	—	1	μA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu\text{s}$	—	—	550	A
Clamping Voltage	V_C	$I_{PP} = 550\text{A}, t_p = 8/20\mu\text{s}$	—	13	17	V
Junction Capacitance	C_j	$V_R = 0\text{V}, T = 25^\circ\text{C}, f = 1\text{MHz}$	—	1500	—	pF



Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

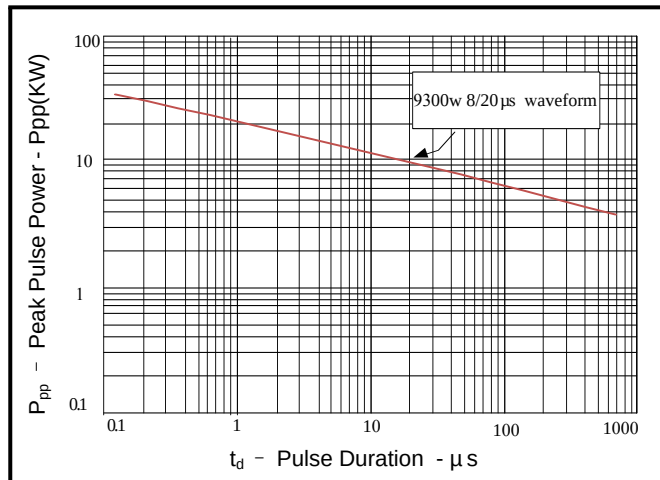


Figure 2: Power Derating Curve

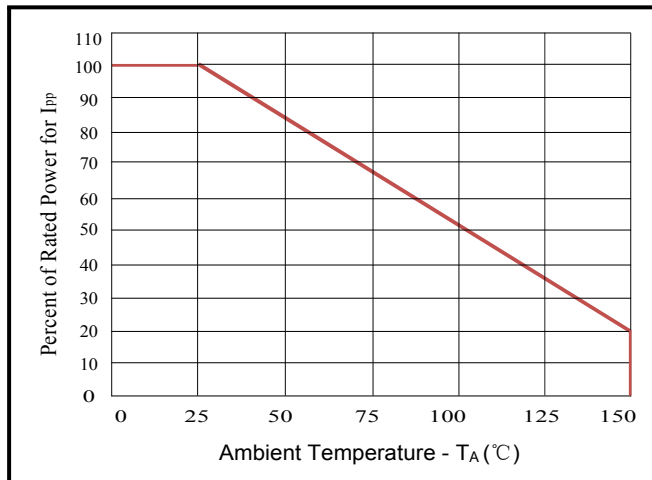


Figure 3: Pulse Waveform

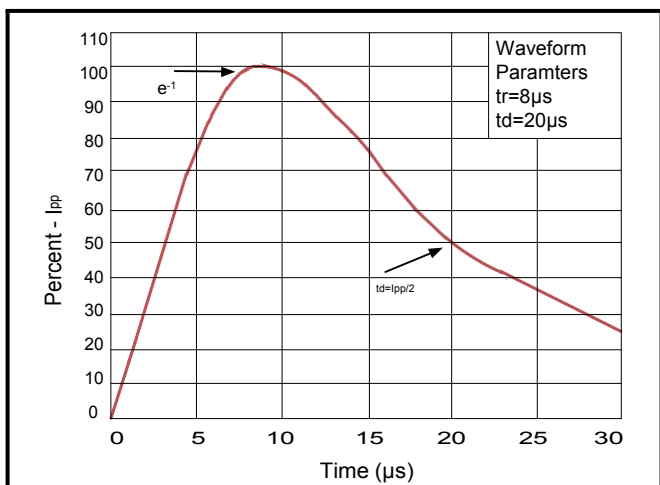
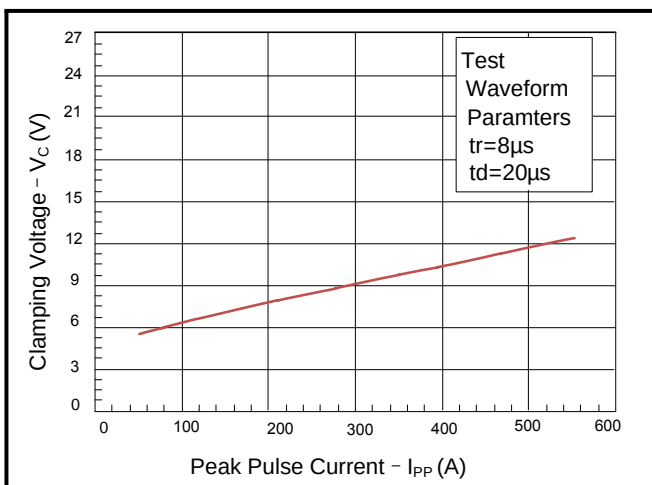


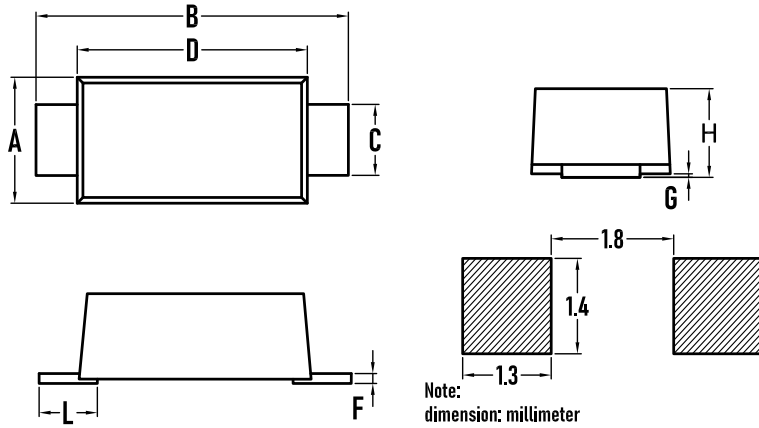
Figure 4: Clamping Voltage vs. I_pp



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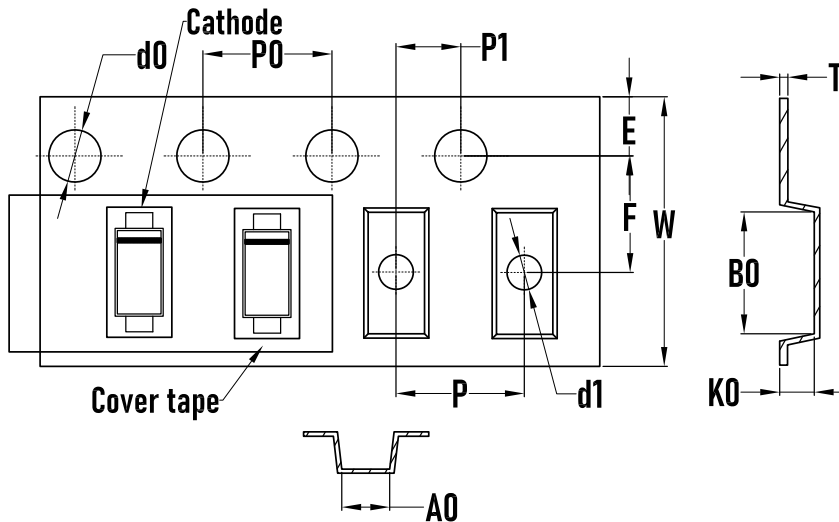
TVS Protection Diode

Package Mechanical Data - SOD-123FL



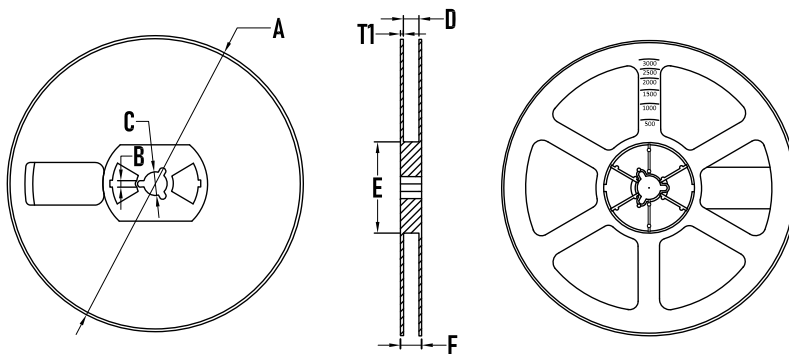
SYMBOL	MILLIMETER		
	MIN.	Typ.	MAX.
A	1.50	1.75	2.00
B	3.40	3.65	3.90
C	0.70	0.95	1.20
D	2.50	2.70	2.90
F	0.05	0.15	0.26
G	0.00	—	0.10
H	0.95	1.15	1.35
L	0.35	0.63	0.90

Packaging Tape - SOD-123FL



SYMBOL	MILLIMETER
A0	2.10±0.1
B0	4.0 ±0.1
d0	1.5±0.1
d1	1.0±0.1
E	1.75±0.1
F	3.50±0.1
K0	1.25±0.1
P	4.00±0.1
P0	4.00±0.1
P1	2.00±0.1
W	8.00±0.1
T	0.2±0.02

Packaging Reel



SYMBOL	MILLIMETER
A	177.8±0.2
B	2.7±0.2
C	13.5±0.2
D	9.6±0.3
E	54.5±0.2
F	12.3±0.3
T1	1.0±0.2
Quantity	3000PCS

